NSN 5961-00-081-6749

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View Online at https://aerobasegroup.com/nsn/5961-00-081-6749 **Inclosure Material:** Metal **Overall Length:** 0.546 inches **Overall Diameter:** 1.046 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Thread Size:** 0.190 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 30.0 breakdown voltage, collector-to-emitter, base open and 25.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 5.00 amperes source cutoff current and 7.50 amperes source cutoff current **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Case acts as third terminal; junction pattern arrangement: npn **Thread Series Designator:** Unf **Terminal Type And Quantity:** 2 tab, solder lug Shelf Life: N/a **Unit Of Measure: Demilitarization:** No

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